

## **EMI Ferrite Chip Beads**

Steward's surface mount ferrite chips provide compact, cost effective EMI filtering for densely packed PCB designs. The small footprint enables placement very close to troublesome high frequency devices. Our proprietary SMT construction yields rugged components with impedance versus frequency characteristics superior to those of similar products.

## Features:

•Small footprint •Excellent retention under bias •Rugged, monolithic construction •Superior impedance vs. frequency characteristics •Economical •Broad range of sizes (from 0402 up to 2220 and 3312) •Broad range of impedance values and current ratings •Also offered in lead free

## Applications:

•Filtering of power input pins and devices using high speed clocks •Filtering of low frequency input/output signals of shielded enclosures •High frequency filtering of medium speed clocks and video signals •Prevention of oscillations in high frequency amplifiers •Data bus filtration •Discrete component filtration in power supplies •Telecom Products

## Test Specifications:

•Maximum current ratings are determined by testing to a maximum temperature rise of 40°C with continuous operating current Tested with: •E4991A (100kHz - 3.0 GHz) or HP8753 (to 6 GHz) Network/Spectrum Analyzer •HP43961A Impedance Test Kit •HP16193A Test Fixture or Inter-Continental Microwave custom fixtures •HP16200A DC Bias Adapter •Philips PM2811 DC Power Supply •Ambient Temperature 23.5°C ± 2° •Bandwidth 3 kHz •Sweep Time 423 ms •Impedance is rated at ± 25% @100MHz

STEWARD	PART NU	MBERING SYST	EM		
DM	1612	X	560	_R_	- <u>00</u>
PRODUCT SERIES CODE	PART SIZE CODE	RATED CURRENT CODE	IMPEDANCE VALUE CODE	PACKAGING CODE	ADDITIONAL DESCRIPTION

DM Ultra High Current Chips (10 Amps +)

HI High Current Chips ( > 3 Amps)

Mid Current Chips (1-2.5 Amps)

High Retention Under Bias

LI Low Current Chips (< 1 Amp and < 400 Ohms)

HZ High Impedance Chips (<1 Amp and > 400 Ohms)

DA Chip Array (< 1 Amp)



Chip Bead



IMPEDANCE (Z)

Ambient Operating Temperature Range: -55°C to +125°C

PART NUMBER	METRIC (EIA) PKG. SIZE	IMPEDANCE (Z) TYPICL OHMS @  100MHz 500MHz 1GHz			DCR MAX OHMS	RATED I MAX (continuous) mA		
	Ultra H	ligh C	urrent	Chips	;			
DM1612X560R-00	4131 (1612)	56	90	100	0.004	10,000		
DM3312X101R-00	8531 (3312)	100	175	225	0.004	10,000		
	High Current Chips							
HI0603P600R-00	1608 (0603)	60	90	95	0.040	3,000		
HI0805Q310R-00	2012 (0805)	31	42	46	0.025	4,500		
HI0805R800R-01		80	109	89	0.016	5,000		
HI0805O121R-00		120	128	72	0.020	3,500		
HI1206T500R-00	3216 (1206)	50	73	80	0.010	6,000		
HI1206N800R-00		80	120	129	0.035	3,000		
HI1206N101R-00		100	144	150	0.035	3,000		
HI1206P121R-00		120	168	124	0.030	4,000		
HI1206T161R-00		160	220	160	0.018	6,000		

PART NUMBER	(EIA) PKG. SIZE	TYF	PICL OHM	DCR MAX OHMS	MAX (continuous) mA	
Hi	gh Cur	rent C	Chips	(Contin	ued)	
HI1806T600R-00	4516 (1806)	60	102	107	0.010	6,000
HI1812T800R-00	4532 (1812)	80	121	129	0.010	6,000
HI1812V101R-00		100	148	156	0.010	8,000
HI2220T101R-00	5650 (2220)	100	148	152	0.006	6,000
HI2220R151R-00		150	215	196	0.015	5,000
HI2220R181R-00		180	260	230	0.020	5,000
HI2220P171R-00		170	318	349	0.030	4,000
HI2220P251R-00		250	172	91	0.015	4,000
HI2220P271R-00		270	360	250	0.035	4,000
HI2220R301R-00		300	190	100	0.020	5,000
HI2220Q401R-00		400	159	99	0.025	4,500
HI2220P551R-00		550	670	343	0.035	4,000

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Page 2									
PART NUMBER	METRIC (EIA) PKG. SIZE	TYF	PEDANCE PICL OHM z 500MH	DCR MAX OHMS	RATED I MAX (continuous) mA				
Hi	gh Cur	rent C	hips	(Contin	ued)				
HI2220P601R-00		600	184	106	0.025	4,000			
HI2220P701R-00		700	140	90	0.025	4,000			
HR2220P601R-00		600	150	75	0.025	4,000			
HR2220V801R-00		800	125	75	0.010	8,000			
HI2520P501R-00	6350 (2520)	500	215	133	0.020	4,000			
HI2520P601R-00		600	639	165	0.015	4,000			
HI2520P751R-00		750	173	114	0.020	4,000			
Mid Current Chips									
MI0603J600R-00	1608 (0603)	60	92	103	0.100	1,000			
MI0603J680R-00		68	106	99	0.100	1,000			
MI0603M121R-00		120	195	155	0.050	2,500			
MI0603L301R-00		300	225	120	0.100	2,000			
MI0603J601R-00		600	400	200	0.200	1,000			
MI0603K300R-00		30	43	44	0.090	1,500			
MI0805J070R-00	2012 (0805)	7	23	28	0.100	1,000			
MI0805K110R-00		11	18	19	0.060	1,500			
MI0805K260R-00		26	43	45	0.060	1,500			
MI0805K400R-00		40	60	63	0.050	1,500			
MI0805M221R-00		220	274	167	0.050	2,500			
MI0805L301R-00		300	271	147	0.100	2,000			
MI0805K601R-00		600	275	140	0.100	1,500			
MI1206K260R-00	3216 (1206)	26	38	40	0.060	1,500			
MI1206K310R-00	-	31	45	50	0.045	1,500			
MI1206K900R-00		90	142	158	0.080	1,500			
MI1206K900R-00						1,500			

PART NUMBER	METRIC (EIA) PKG. SIZE	TY	PEDANCE PICL OHMS Hz 500MHz	DCR MAX OHMS	RATED I MAX (continuous) mA				
N	lid Cur	rent C	Chips (0	Continu	ed)				
MI1206L501R-00		500	150	82	0.060	2,000			
MI1206K601R-00		600	250	130	0.080	2,000			
MI1210K600R-00	3225 (1210)	60	90	95	0.035	1,500			
MI1812K121R-00	4532 (1812)	120	198	213	0.055	1,500			
Low Current Chips									
Ll0402E300R-00	1005 (0402)	30	50	57	0.300	500			
Ll0402E600R-00		60	90	93	0.300	500			
Ll0402D121R-00		120	205	195	0.400	400			
Ll0402B301R-00		300	454	351	0.800	200			
Ll0603G800R-00	1608 (0603)	80	120	107	0.200	700			
Ll0603G121R-00		120	156	113	0.200	700			
Ll0603G221R-00		220	279	168	0.300	700			
Ll0603D301R-00		300	286	165	0.350	400			
Ll0805H750R-00		75	112	113	0.150	800			
Ll0805H121R-00		120	167	129	0.150	800			
Ll0805H151R-00		150	207	138	0.150	800			
Ll0805G301R-00		300	248	146	0.200	700			
LI1206E310R-00	3216 (1206)	31	43	46	0.200	500			
LI1206H121R-00		120	144	135	0.150	800			
LI1206H151R-00		150	173	123	0.150	800			
LI1806E800R-00	4516 (1806)	80	117	124	0.300	500			
LI1806E101R-00		100	131	130	0.300	500			
LI1806C151R-00		150	219	227	0.500	300			

PART NUMBER	METRIC (EIA) PKG. SIZE	TYI	PEDANCE PICL OHMS z 500MH	DCR MAX OHMS	RATED I MAX (continuous) mA			
	High	Impe	dance	Chips				
HZ0402A601R-00	402A601R-00 1005 (0402) 600 644 399 1.000 10							
HZ0603C601R-00	1608 (0603)	600	338	171	0.450	300		
HZ0603C651R-00		650	650	936	0.600	300		
HZ0603B102R-00		1,000	376	187	0.600	200		
HZ0603B112R-00		1,100	1,300	850	0.800	200		
HZ0603A222R-00		2,200	375	175	1.500	100		
HZ0805G471R-00	2012 (0805)	470	286	150	0.350	700		
HZ0805E601R-00		600	304	151	0.300	500		
HZ0805D102R-00		1,000	328	168	0.350	400		
HZ0805D152R-00		1500	333	166	0.400	400		
HZ0805C202R-00		2,000	345	175	0.500	300		

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PART NUMBER	METRIC (EIA) PKG. SIZE	IMPEDANCE (Z) TYPICL OHMS @  100MHz 500MHz 1GHz			DCR MAX OHMS	RATED I MAX (continuous) mA	
High	Imped	dance	Chips	(Cont	inued)		
HZ1206E601R-00	3216 (1206)	600	202	103	0.300	500	
HZ1206D102R-00		1,000	185	100	0.400	400	
HZ1206C202R-00		950	180	100	0.500	300	
4-Line Chip Arrays							
DA1206E300R-00	3216 (1206)	30	55	64	0.300	500	
DA1206D600R-00		60	115	60	0.200	400	
DA1206C121R-00		120	181	151	0.200	300	
DA1206D301R-00		300	437	245	0.400	400	
DA1206B601R-00		600	475	230	0.600	200	
DA1206B102R-00		1,000	520	240	0.800	200	

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		Chip Si	ze			Land Patterns f	or Reflov	v Solde	ering
	Metric (EIA) Pkg. Size	A mm (inches)	B mm (inches)	C mm (inches)	D mm (inches)		L**	G	н
	1005 (0402)	1.01 ± 0.18 (0.040 ± 0.007)	$0.50 \pm 0.20$ (0.020 ± 0.008)	$0.50 \pm 0.20$ $(0.020 \pm 0.008)$	0.30 MAX (0.012 MAX)		2.10 (0.083)	0.50 (0.020)	0.55 (0.022)
	1608 (0603)	1.60 ± 0.15 (0.063 ± 0.006)	$0.80 \pm 0.15$ (0.031 ± 0.006)	$0.80 \pm 0.15$ (0.031 ± 0.006)	$0.36 \pm 0.15$ (0.014 ± 0.006)		2.60 (0.102)	0.60 (0.023)	0.80 (0.031)
× /-	2012 (0805)	$2.00 \pm 0.20$ $(0.079 \pm 0.008)$	1.25 ± 0.20 (0.049 ± 0.008)		3.23 (0.127)	0.66 (0.026)	1.47 (0.058)		
A B C C	B 2012   $2.00 \pm 0.20$   $1.25 \pm 0.20$   $1.25 \pm 0.20$   $0.51 \pm 0.25$   $0.51 \pm 0.25$   Land Pattern for Re Soldwing	Land Pattern for Reflo	3.23 (0.127)	0.66 (0.026)	1.47 (0.058)				
	3216 (1206)	3.20 ± 0.20 (0.126 ± 0.008)	1.60 ± 0.20 (0.063 ± 0.008)	1.10 ± 0.20 (0.043 ± 0.008)	$0.51 \pm 0.25$ $(0.020 \pm 0.010)$	- G	4.40 (0.173)	2.20 (0.087)	1.40 (0.055)
) Dr	3225 (1210)	$3.20 \pm 0.20$ (0.126 ± 0.008)	$2.50 \pm 0.20$ (0.098 ± 0.008)	1.40 ± 0.20 (0.055 ± 0.008)	$0.46 \pm 0.20$ (0.018 ± 0.008)	Chip Bead	4.06 (0.160)	1.62 (0.084)	2.92 (0.115)
	4030 (1612)	4.06 ± 0.20 (0.160 ± 0.008)	3.05 ± 0.20 (0.120 ± 0.008)	2.28 ± 0.20 (0.090 ± 0.008)	$0.46 \pm 0.20$ (0.018 ± 0.008)		8.64 (0.340)	2.13 (0.084)	4.06 (0.160)
	4516 (1806)	4.50 ± 0.25 (0.177 ± 0.010)	1.60 ± 0.25 (0.063 ± 0.010)	1.60 ± 0.25 (0.063 ± 0.010)	$0.51 \pm 0.25$ $(0.020 \pm 0.010)$		5.70 (0.224)	2.70 (0.106)	1.40 (0.055)
	4532 (1812)	4.50 ± 0.25 (0.177 ± 0.010)	3.20 ± 0.25 (0.126 ± 0.010)	1.40 ± 0.25 (0.055 ± 0.010)	$0.46 \pm 0.20$ (0.018 ± 0.008)		5.90 (0.232)	2.57 (0.101)	4.22 (0.166)
Equivalent Circuit	5650 (2220)	5.59 ± 051 (0.220 ± 0.020)	5.08 ± 0.25 (0.200 ± 0.010)	3.45 ± 0.25 (0.136 ± 0.010)	$0.76 \pm 0.25$ $(0.030 \pm 0.008)$		9.19 (0.362)	3.07 (0.121)	6.10 (0.240)
1	6350 (2520)	6.40 ± 0.51 (0.252 ± 0.020)	5.00 ± 0.25 (0.197 ± 0.010)	3.00 ± 0.25 (0.118 ± 0.010)	$0.76 \pm 0.25$ $(0.030 \pm 0.010)$		9.50 (0.374)	3.81 (01507)	6.10 (0.240)
	8530 (3312)	8.50 ± 0.20 (0.335 ± 0.008)	$3.05 \pm 0.20$ (0.120 ± 0.008)	2.28 ± 0.20 (0.090 ± 0.008)	$0.51 \pm 0.25$ $(0.020 \pm 0.010)$		13.08 (0.515)	6.48 (0.255)	4.06 (0.160)
	4-Li	ne Chip A	rray Size			Land Patterns f	or Reflov	v Solde	ering
A B	Metric (EIA) Pkg. Size	A mm (inches)	B mm (inches)	C mm (inches)	D mm (inches)	L*	' G	н	E
	3216 (1206)	3.20 ± 0.20 (0.126 ± 0.008)	1.60 ± 0.20 (0.063 ± 0.008)	0.80 ± 0.20 (0.031 ± 0.008)	$0.40 \pm 0.15$ (0.016 ± 0.006)	2.7 (0.10		2.44 (0.096)	0.80 (0.031)
E		Recom	mended Sold	Ū		<del></del>	8 7	6	5
Equivalent Circuit    8 7 6 5		TEMPERATURE (**C) [*F] [47] [47] [47]	PRE-HEATING  eo SECONOS		ATURAL OOLING	 		G 3 (	E
1 2 3 4		-	100 SECONDS	5 - 10 SECONDS 60 SEC	CONDS		r wave solde nm (0.030") to		nension